

ESD103-B1-02ELS

Bi-directional ESD protection device, 15 V, 0.09 pF, 0201

Product description

ESD protection device with a bi-directional symmetric I/V characteristic and excellent clamping performance, extremely low capacitance and high linearity for mobile device antenna.

Feature list

- ESD/transient protection according to:
 - IEC61000-4-2 (ESD): ± 14 kV (air) / ± 10 kV (contact)
- Bi-directional maximum working voltage: $V_{WM} = \pm 15$ V
- Line capacitance: $C_L = 0.09$ pF at $f = 1$ GHz
- Clamping voltage: $V_{cl} = 48$ V at $I_{TLP} = 16$ A with $R_{dyn} = 1.8 \Omega$
- Very low leakage current: $I_L = 0.1$ nA
- Small form factor SMD size, low profile ($0.62 \times 0.32 \times 0.31$ mm³)



Potential applications

- RF antennas and interfaces (LTE, WLAN)

Product validation

Qualified for industrial applications according to the relevant tests of JEDEC47/20/22.

Device information

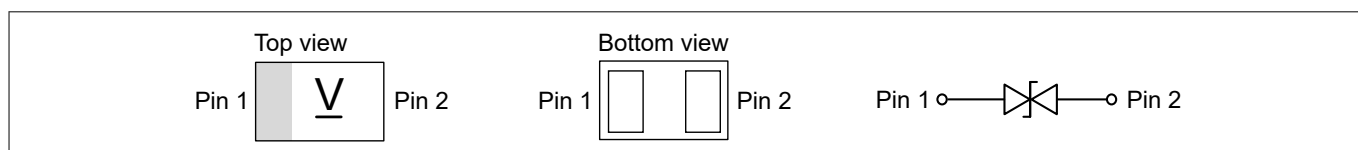


Figure 1 Pin configuration and schematic diagram

Table 1 Part information

Product name / Ordering code	Package	Pin configuration	Marking	Pieces / Reel
ESD103-B1-02ELS/ESD103B102ELSE6327XTSA1	TSSLP-2-4	1 line, bi-directional	V	15 k

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1 Absolute maximum ratings

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Table 2 Absolute maximum ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Values		Unit	Note or test condition
		Min.	Max.		
Working voltage	V_{WM}	-15	+15	V	
ESD discharge voltage	V_{ESD} (contact)	-10	+10	kV	Discharge network: $R = 330\ \Omega$, $C = 150\ \text{pF}$ ¹⁾
	V_{ESD} (air)	-14	+14		
Operating temperature	T_{op}	-55	+125	$^\circ\text{C}$	
Storage temperature	T_{stg}	-65	+150		

Attention: Stresses above the maximum values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings. Exceeding only one of these values may cause irreversible damage to the component.

¹ Based on IEC61000-4-2.

2 Electrical characteristics

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Note: $T_A = 25^\circ\text{C}$, unless otherwise specified. Device is electrically symmetrical.

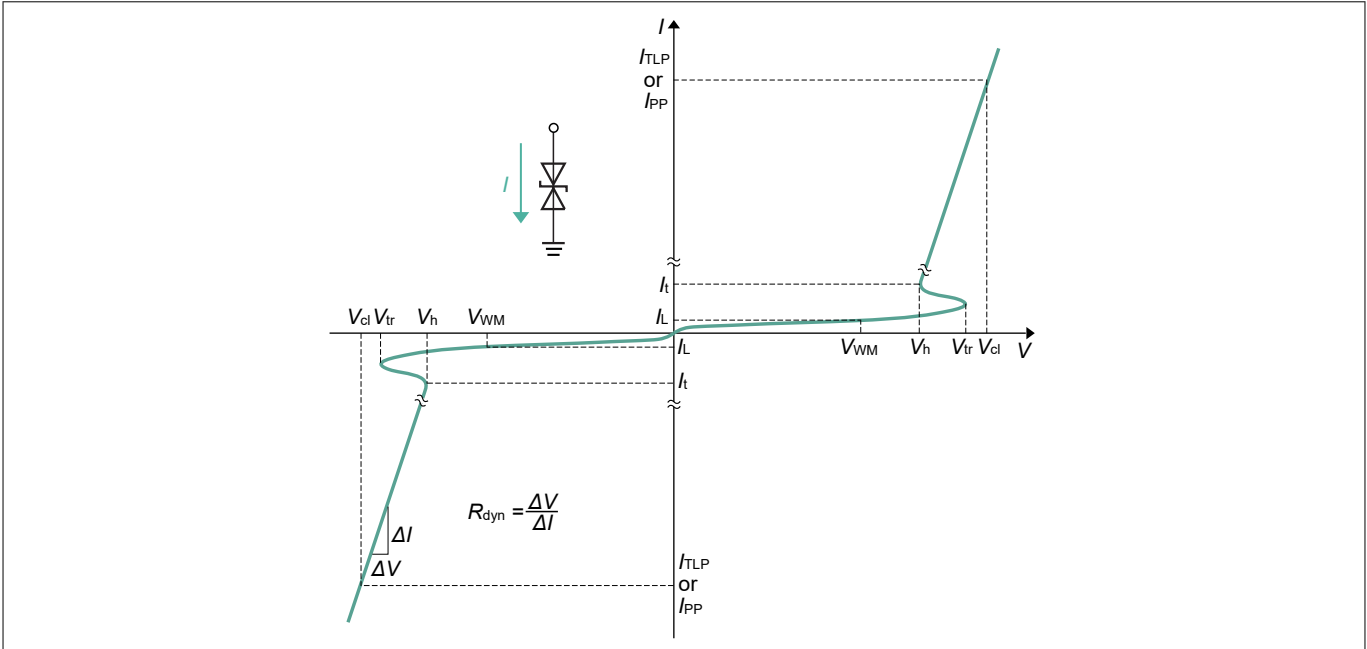


Figure 2 **I/V characteristic curve**

Table 3 **I/V characteristic parameters**

Symbol	Parameter
I_h	Holding current
I_L	Leakage current
I_{PP}	Peak pulse current, based on IEC61000-4-5
I_t	Test current
I_{TLP}	TLP current
R_{dyn}	Dynamic resistance
V_{cl}	Clamping voltage
V_h	Holding voltage
V_t	Test voltage
V_{tr}	Trigger voltage
V_{WM}	Maximum working voltage

Note: For more detailed explanation of electrical parameters, refer to [1].

2 Electrical characteristics

Table 4 DC characteristics

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Trigger voltage ²⁾	V_{tr}	-	21	-	V	
Leakage current	I_L	-	0.1	50	nA	$V_{WM} = 15\text{ V}$

Table 5 AC characteristics

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Line capacitance	C_L	-	0.13	0.2	pF	$V = 0\text{ V}, f = 1\text{ MHz}$
		-	0.09	-		$V = 0\text{ V}, f = 1\text{ GHz}$
Series inductance	L_S	-	0.2	-	nH	Extracted from S-parameters

Table 6 Protection characteristics

Parameter	Symbol	Values			Unit	Note or test condition
		Min.	Typ.	Max.		
Clamping voltage (TLP) ^{3) 4)}	V_{cl}	-	20	-	V	$I_{TLP} = 1\text{ A}$
		-	36	-		$I_{TLP} = 8\text{ A}$
		-	48	-		$I_{TLP} = 16\text{ A}$
Dynamic resistance ³⁾	R_{dyn}	-	1.8	-	Ω	

²⁾ Verified by design.

³⁾ TLP parameters: $Z_0 = 50\ \Omega$, $t_p = 100\text{ ns}$, $t_r = 0.6\text{ ns}$, averaging window 30-60 ns.

⁴⁾ Refer to application note [2].

3 Typical characteristic diagrams

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Note: $T_A = 25^\circ\text{C}$, unless otherwise specified.

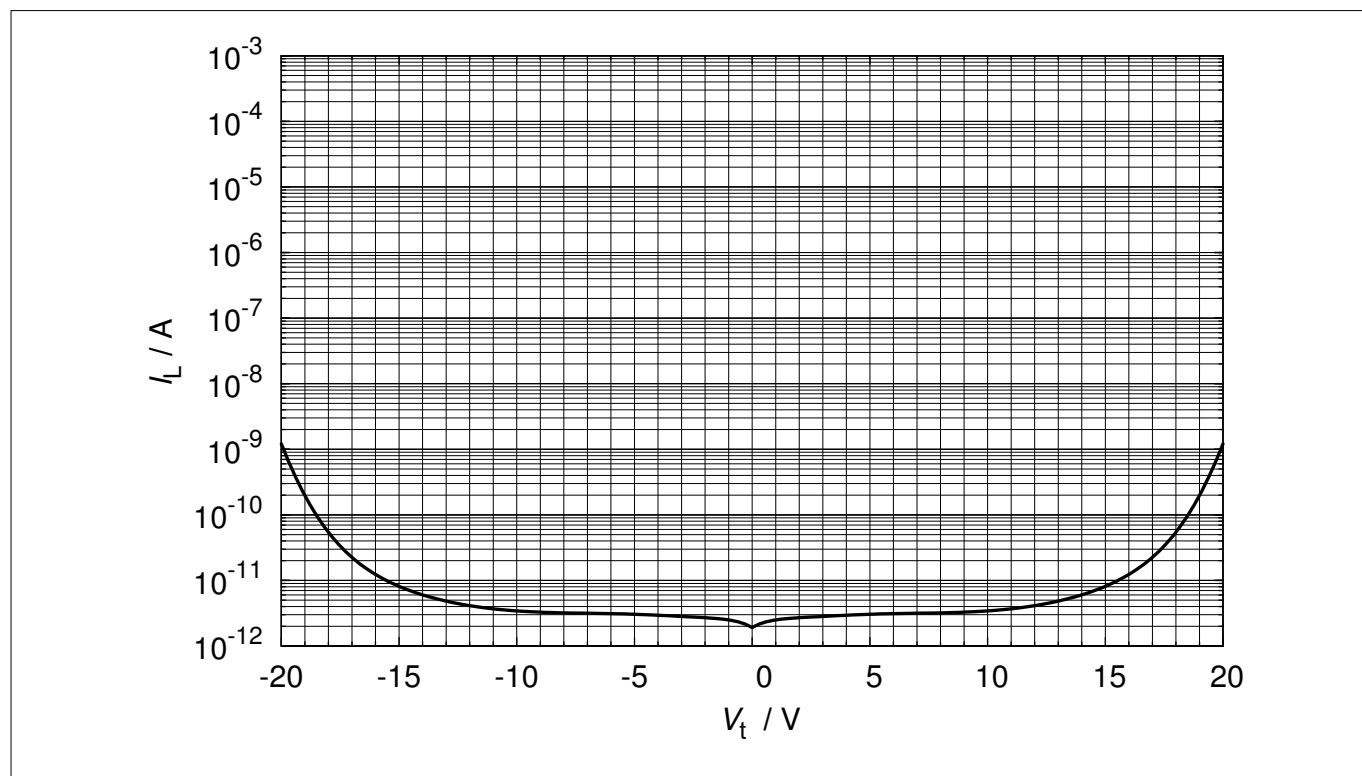


Figure 3 Leakage current $I_L = f(V_t)$

3 Typical characteristic diagrams

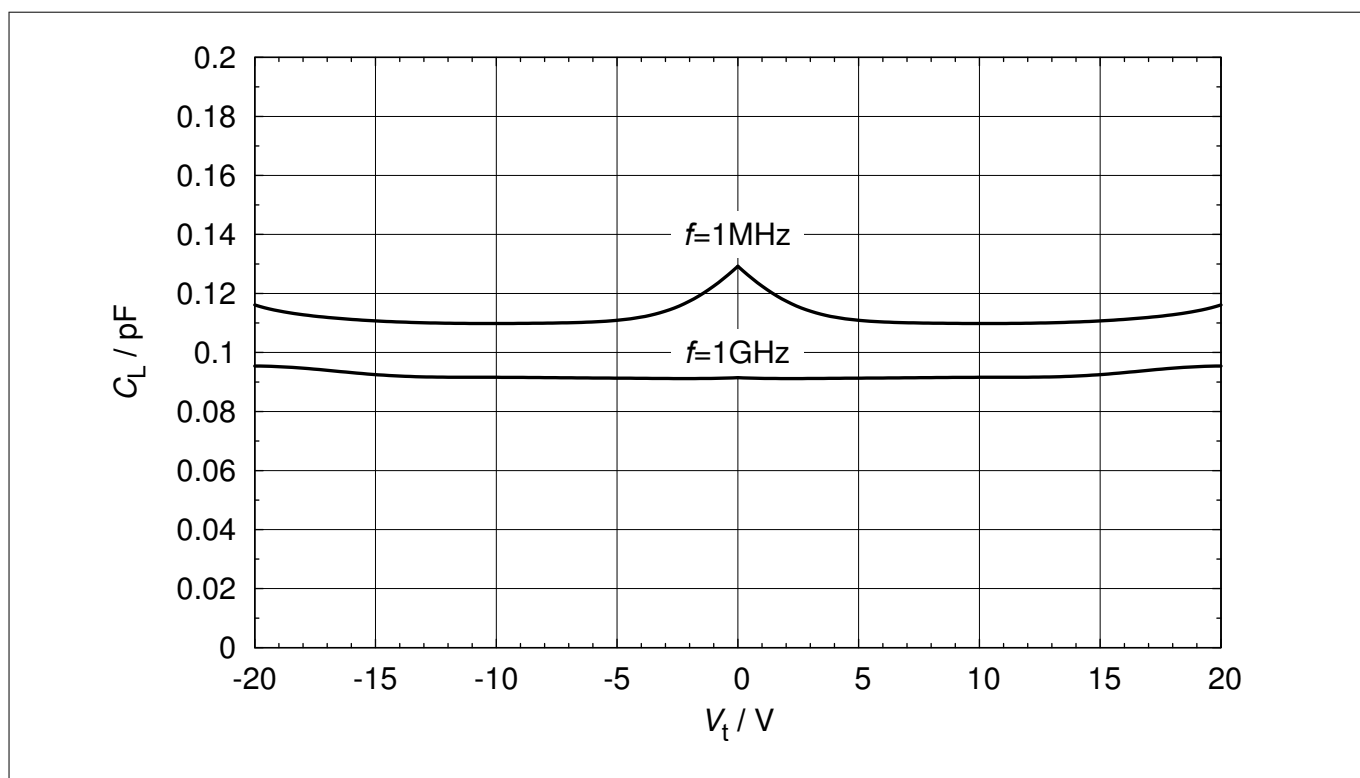


Figure 4 Line capacitance $C_L = f(V_t)$, $f = 1\text{ MHz}$, 1 GHz

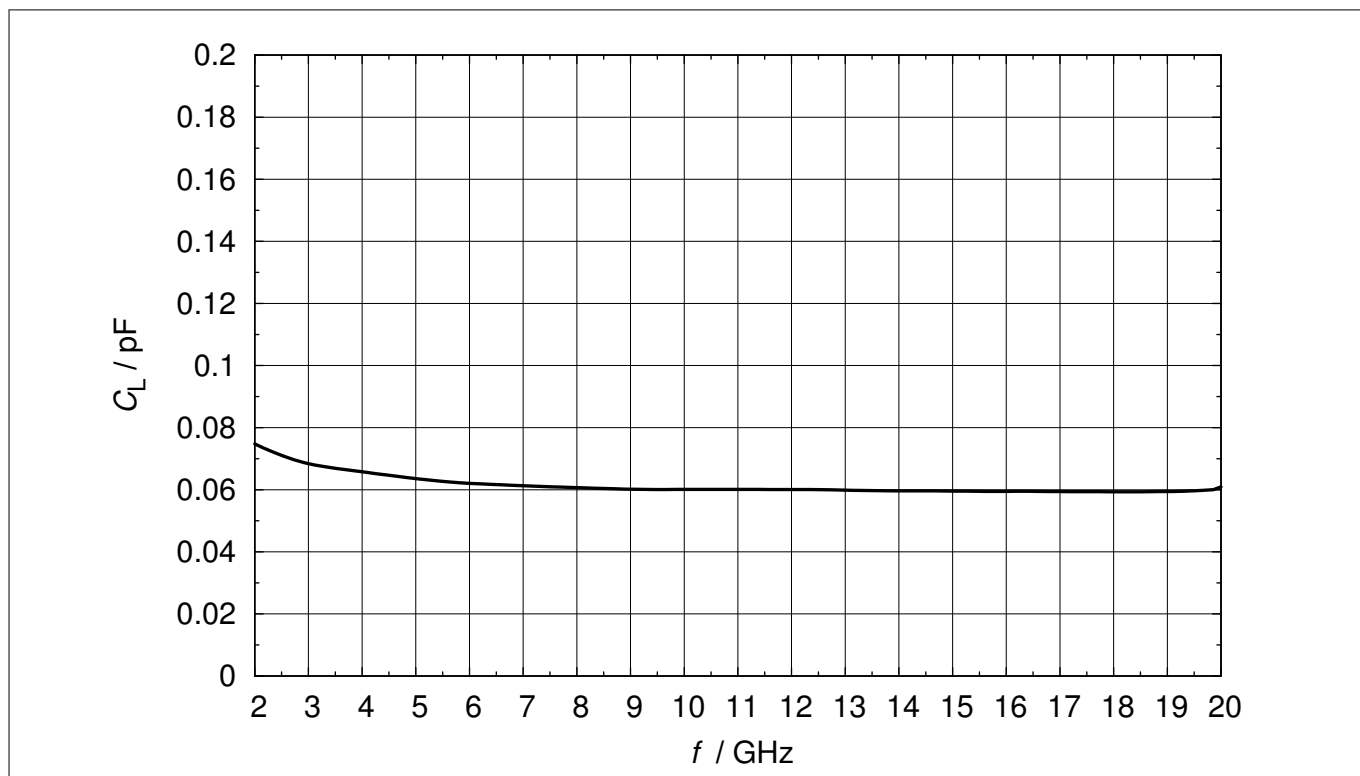


Figure 5 Line capacitance: $C_L = f(f)$, $V_t = 0\text{ V}$

3 Typical characteristic diagrams

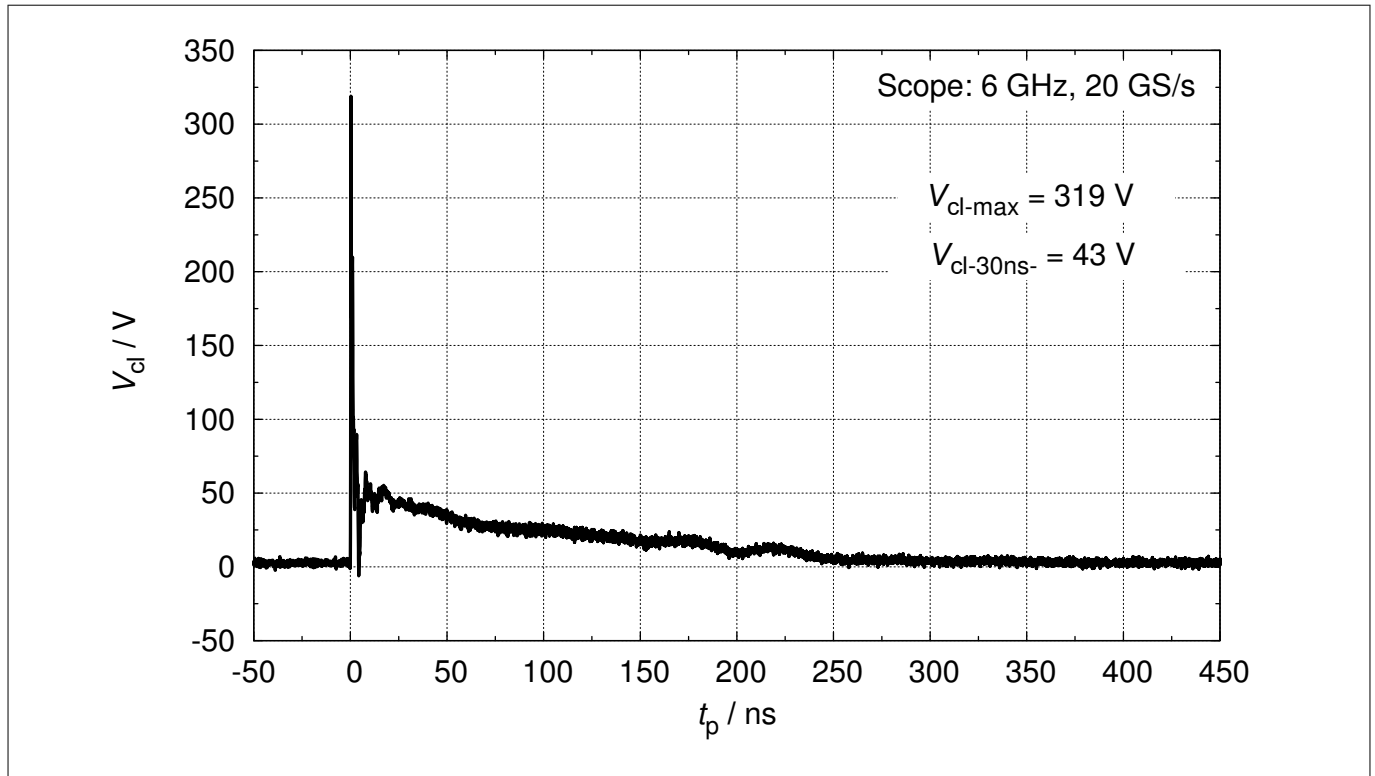


Figure 6 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 8 kV positive pulse based on IEC61000-4-2

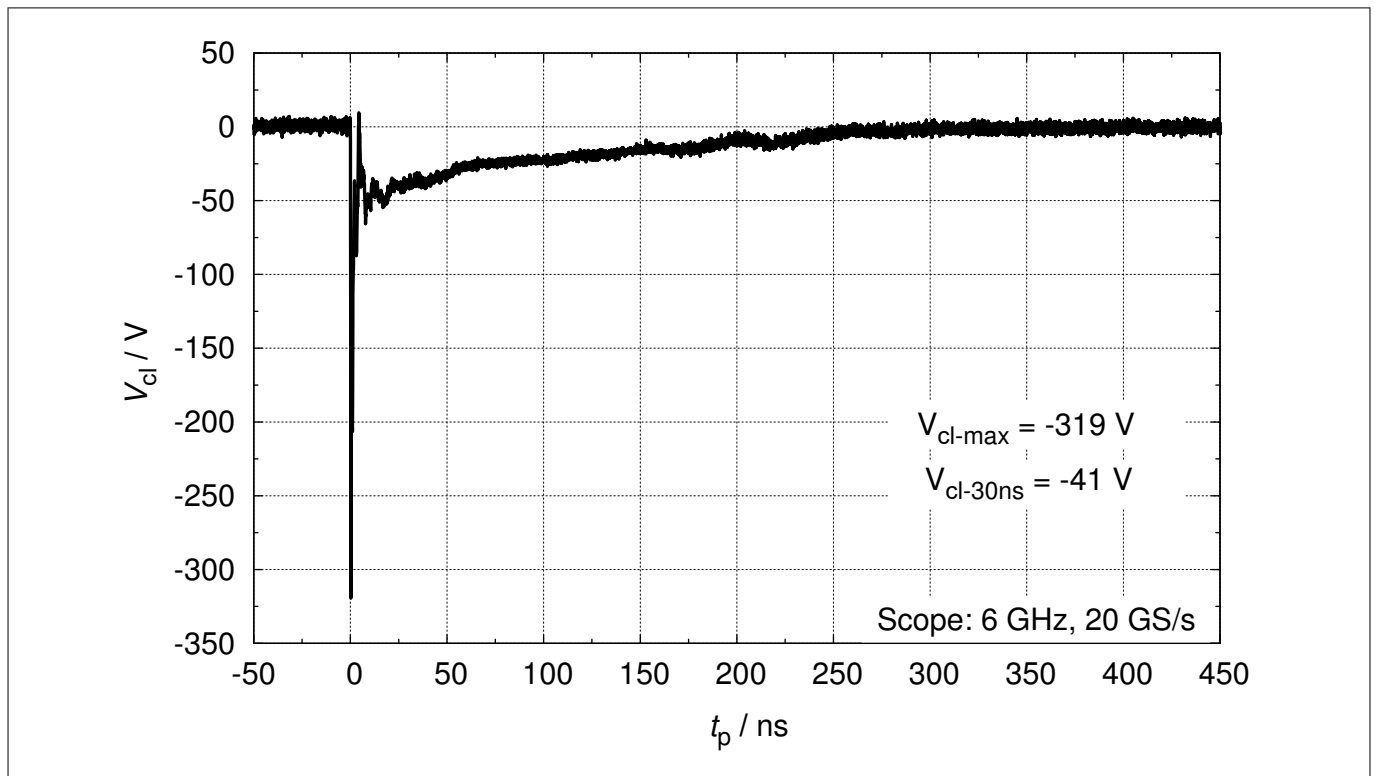


Figure 7 Clamping voltage (ESD): $V_{cl} = f(t_p)$, 8 kV negative pulse based on IEC61000-4-2

3 Typical characteristic diagrams

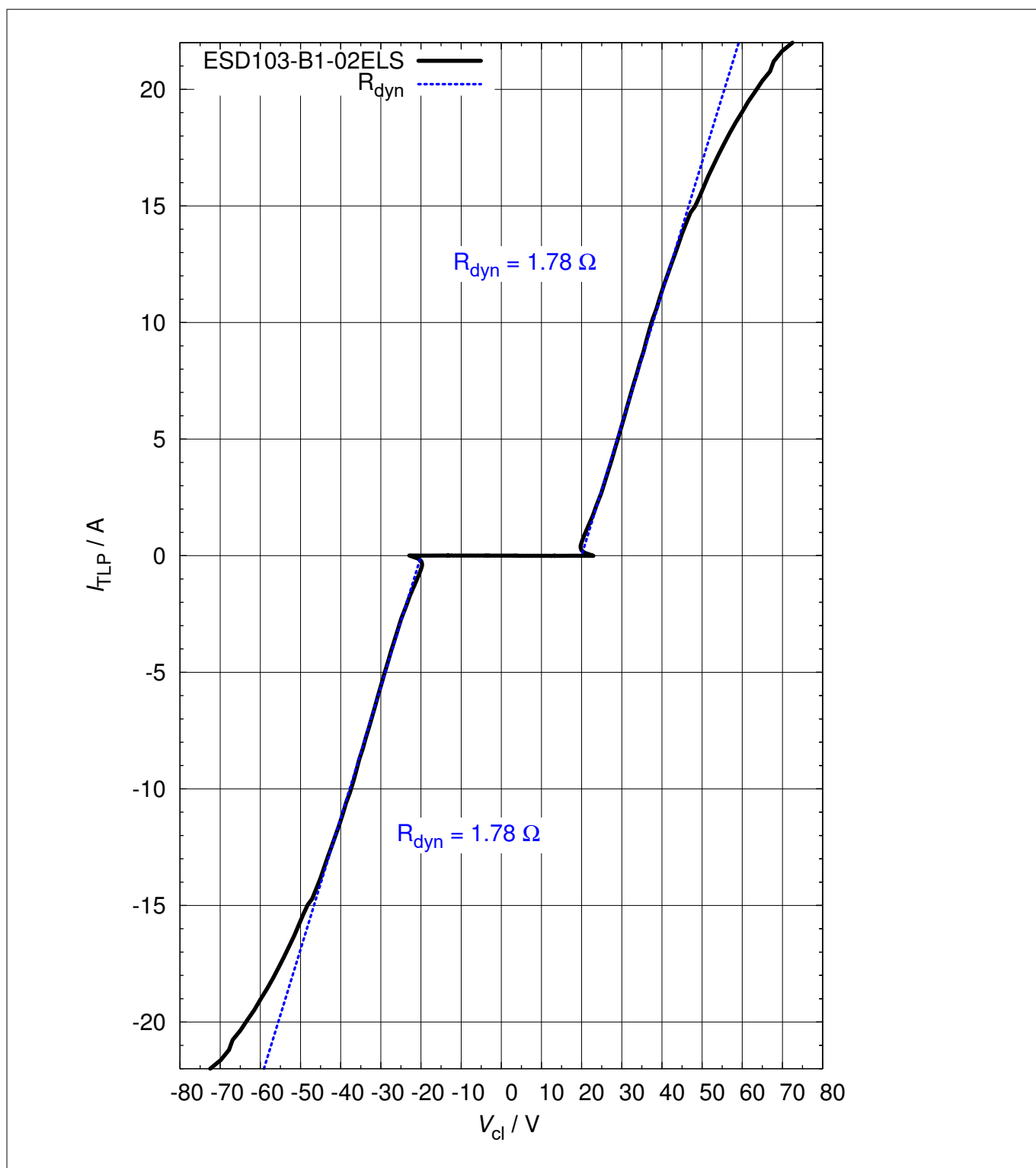


Figure 8 Clamping voltage (TLP): $I_{TLP} = f(V_{cl})$

4 Package information TSSLP-2-4

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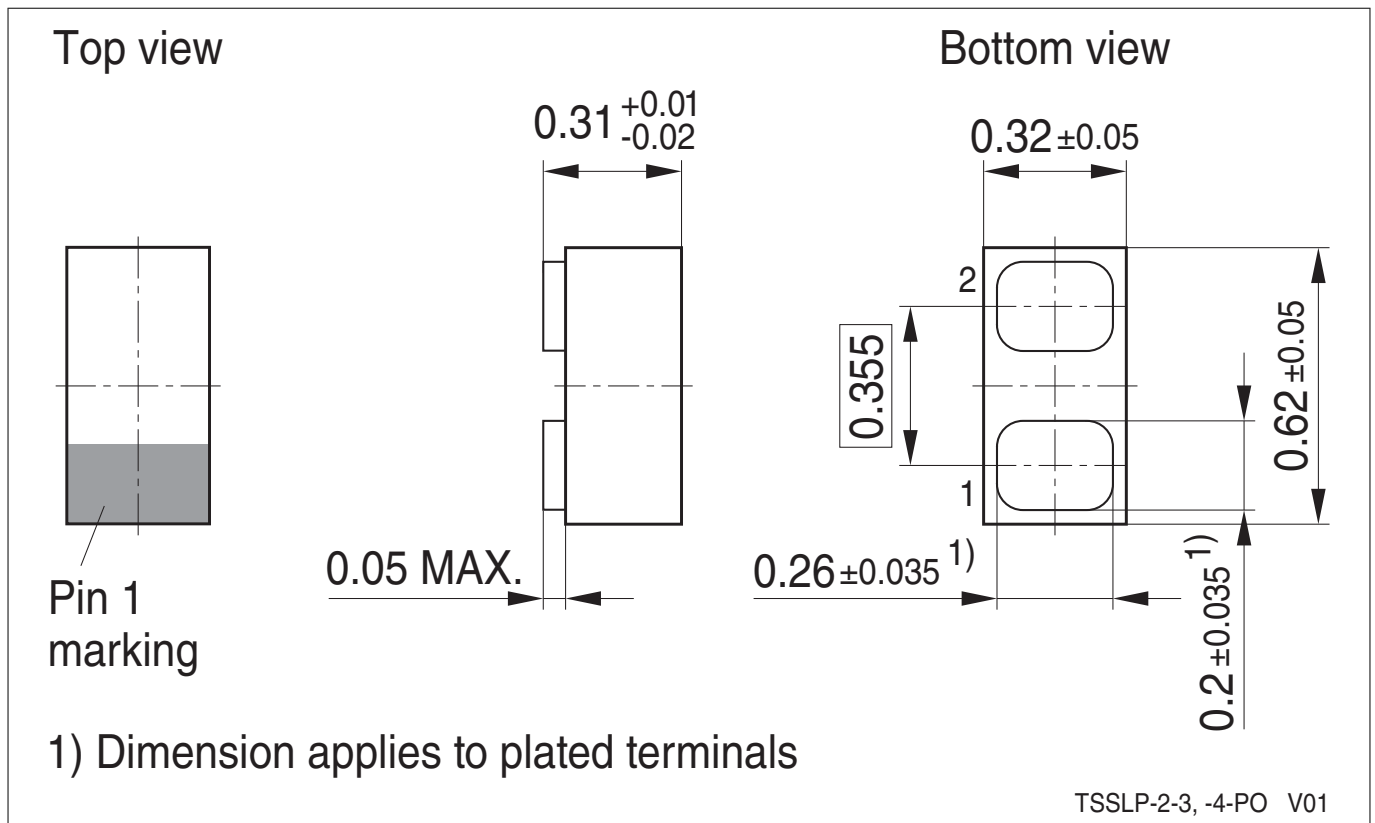


Figure 9 TSSLP-2-4 package

Note: For package information including footprint, packing and assembly recommendation refer to:

<https://www.infineon.com/package/PG-TSSLP-2-4/>

References

- [1] Infineon Technologies AG: *Understanding ESD protection device characteristics product information*; [Available online](#)
- [2] Infineon Technologies AG: *Effective ESD protection design at system level using VF-TLP characterization methodology application note*; [Available online](#)

Revision history**Revision history**

Document version	Date of release	Description of changes
1.3	2014-06-12	Table 5 updated
2.0	2023-02-02	New datasheet layout
2.1	2024-07-12	Typos fixed

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Edition 2024-07-12

Published by

**Infineon Technologies AG
81726 Munich, Germany**

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**Document reference
IFX-ahl1647426227436**

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